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Article

Adsorption of Greenhouse Decomposition Products on Ag₂O–SnS₂ and CuO–SnS₂ Surfaces

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 NH_3 gas sensors in terms of moderate adsorption distance, large adsorption energy, charge transfer, and frontier molecular orbital theory, while $CuO-SnS_2$ is more suitable as a C_2H_2 gas sensor.

1. INTRODUCTION

Greenhouse cultivation is favored by more and more farmers for advancing or delaying the planting season, increasing planting density, and bringing greater economic benefits.^{1,2} With the continuous improvement of cultivation technology, the scale of greenhouse cultivation is becoming larger and larger.^{3,4} However, because of the relative isolation of the internal and external environment of the greenhouse, temperature, humidity, moisture, and other factors are relatively stable in the hut, it is easy for gases to accumulate in the hut, which may endanger crop life at a certain concentration.⁵ Therefore, it is necessary to provide gas sensors that can detect the gas content in the greenhouse to achieve the effect of adjusting the amount and type of the gas content in the greenhouse in time. Besides, gas sensors are easy to popularize because of their low cost, which facilitates the achievement of certain economic benefits.^{6,7} In this paper, NH₃, Cl₂, and C₂H₂ produced in the greenhouse are the main representative gases of the greenhouse through the analysis of these three gases carried out in this research.⁸

In recent years, SnS_2 -based materials have been widely used as gas sensors in the industry due to their large specific surface area and abundant pore structure.¹⁰ Compared with carbon nanotubes, SnS_2 has stronger oxidation resistance, hightemperature stability, and smaller dependence, so SnS_2 is more suitable for gas detection than carbon nanotubes.^{11,12} Therefore, it has become one of the most promising materials in high-temperature and high-pressure environments.^{13,14} However, the reaction of intrinsic SnS_2 to some inert gases is limited, such as CH_4 , C_2H_2 , and H_2 . Fortunately, metal doping modification can adjust the energy gap of the gas-sensing material, thus changing the conductivity of the sensor upon gas adsorption, resulting in improved detection accuracy and adsorption capacity of these gases.¹⁵ Pd, Pt, Au, Ag, Ni, and Co are often used to improve the sensitivity, measurement accuracy, selectivity, and reaction recovery time of gas response. However, the strong surface activity of metal atoms makes the gas sensor easily susceptible to oxidation during a long time operation, which significantly reduces the sensor's stability. Metal oxides, such as Ag₂O and CuO, are the most widely used surface modifications, which show good chemical stability. Salvatore found that SnS_2/SnO_{2-x} mixed phases showed outstanding gas-sensing performance to NH₃.¹⁶ Hao fabricated SnS_2/SnO_2 sensors that exhibited ultrahigh response toward 1 ppm NO₂ at 100 °C, roughly 10.2 times higher than that of pure SnS_2 nanoflowers.¹⁷

In this paper, Ag₂O and CuO-modified SnS₂ (TMO-SnS₂) are proposed as promising greenhouse gas-sensing materials, which can be used to monitor the change in indoor gas concentrations.¹⁸ First, the structure of TMO-SnS₂ is optimized to obtain highly stable structures. Then, the most stable structure is used to analyze its adsorption properties to NH₃, Cl₂, and C₂H₂.^{19,20} The modification and gas-sensing mechanism of

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TMO-SnS₂ are also described. By analyzing the structure optimization, adsorption energy, energy band structure, density of states, and charge transfer, it is found that the modified SnS₂ sensor shows a high gas-sensing response.²¹ The optimal site of gas adsorption can be found through structural optimization analysis, and the model can be used as the model of gas adsorption to analyze the gas-sensing response results. Based on this model, the reaction types and reaction intensities of gas adsorption are analyzed by the adsorption distance, adsorption energy, and charge transfer again through the density of states analysis and frontier molecular orbital theory analysis to further explore the mechanism of gas adsorption afterward, in which the density of states analysis shows that the gas adsorption type and reaction intensity can be determined through the analysis of the frontier molecular orbital theory, which shows that the energy gap of the gas changes and it changes to reflect the conductivity of the gas charge transfer. This study provides a new method for monitoring the concentration of indoor greenhouse gases.²²

2. COMPUTATIONAL DETAILS AND METHODS

All calculations were carried out based on density functional theory (DFT).^{23,24} A periodic boundary model was adopted to avoid the interaction between adjacent cells. The vacuum thickness of the (1 0 1) lattice plane was set to 18.0 Å.^{25,26} The Brillouin zone *k*-point sampling was sampled by $3 \times 3 \times 1$. The electron exchange and correlation energy were calculated by the GGA, and the interaction effect of electrons was treated by the PBE function, whereas a double numerical basis with polarization (DNP) was used.^{27,28} The convergence criterion for energy and force was set as 10^{-5} Ha and 2×10^{-3} Ha/Å, respectively, and the charge density convergence accuracy of the self-consistent field was 1×10^{-6} Ha.^{29,30}

The adsorption energy E_{ads} shows the change in total energy in the process of adsorption, which can be calculated by eq 1.^{31,32} In this formula, $E_{suf/gas}$, E_{suf} , and E_{gas} represent the total energy of the system after the gas molecule's adsorption on TMO-SnS₂, the total energy of the TMO-SnS₂ surface, and the total energy of individual gas molecules before adsorption, respectively.^{33,34}

$$E_{\rm ads} = E_{\rm suf/gas} - E_{\rm suf} - E_{\rm gas} \tag{1}$$

The electron density distribution was calculated by Mulliken population analysis. The charge transfer Q in the adsorption process was obtained by eq 2, where Q_{iso} and Q_{ads} are the total charges of isolated gas and adsorbed gas molecules.^{35,36} Q > 0 means that electrons transfer from gas molecules to the surface of TMO-SnS₂.^{37,38}

$$Q = Q_{ads} - Q_{iso}$$
(2)

The energy gap of the molecular orbital can be calculated by the energy levels of the highest occupied molecular orbital (HOMO) and the lowest occupied molecular orbital (LUMO), defined as eq $3.^{39-42}$ It determines the probability of charge movement in the adsorption system composed of gas molecules and the TMO-SnS₂ surface.⁴³⁻⁴⁶ The narrower the gap, the lower the energy required for electrons to transfer from the valence band to the conduction band.^{47,48}

$$E_{\rm g} = |E_{\rm LUMO} - E_{\rm HOMO}| \tag{3}$$

3. RESULTS AND DISCUSSION

3.1. Structure of SnS₂ and TMO-SnS₂ Surfaces. As shown in Figure 1, the gas molecular structure and intrinsic SnS₂



Figure 1. (a) NH₃ molecule, (b) Cl_2 molecule, (c) C_2H_2 molecule, and (d) SnS_2 molecule. The distance is in Å.

structure are optimized. C_2H_2 and Cl_2 are linear gas molecules, while NH₃ has a three-dimensional tetrahedral structure. The length of the Cl–Cl bond is 2.024 Å, and the lengths of the C–H bond and C–C bond in the C_2H_2 molecule are 1.071 and 1.211 Å, respectively. The N–H bond angle of the NH₃ molecule is 105.35°. The symmetrical N–H bonds of the NH₃ molecule ensure its chemical stability. SnS₂ with a perfect crystal structure is shown in Figure 1d. The two-dimensional structure is beneficial in improving the adsorption performance.^{49,50} The S– Sn bond length of 2.611 Å is appropriate for structural stability, and the axial and circumferential distances are close to this value. In general, SnS₂ is a suitable material for gas adsorption.

Figure 2 shows the most stable doping structure of Ag_2O and CuO-modified SnS₂. The distribution of SnS₂ atoms shows centrosymmetry. The Ag-S bond length (2.406 Å) is slightly shorter than the O–S bond length (3.513 Å), which is consistent with the bond length between heavy metals. This phenomenon illustrates a strong interaction between the Ag and S atoms. The formation energy is -1.626 eV, which confirms the good stability of the interacting structure. The O-S bond length of -doped species is 1.593 Å, which is slightly shorter than the Cu-S bond length of 3.633 Å. It signifies the strong interaction between the O and S atoms. The adsorption energy reaches -1.713 eV, which proves that the structure of CuO-SnS₂ is extremely stable. Based on the Mulliken population, 0.063 e electrons and 0.054 e electrons transfer to SnS₂ from Ag₂O and CuO as electron donors, respectively. This redistribution of charge results in a change in the conductivity of the doping system.

The density of states was analyzed to further study the interaction mechanism of Ag_2O and CuO-modified $SnS_{2\!\prime}$ as shown in Figure 3. After Ag₂O and CuO doping on the SnS₂ surface, the total density of states (TDOS) changes significantly in the range of -2 to -5 eV and -1 to 1 eV. The TDOS of TMO-SnS₂ consists mainly of 3p orbitals of the S atom. According to the analysis of the partial density of states (PDOS), the 3p orbital of S and the 4d orbital of Ag overlap significantly around -4 eV. The orbital hybridization occurs when the Ag atom interacts with the S atom, indicating that the interaction of SnS_2 with Ag_2O mainly comes from the S atom of the SnS_2 . The 3p orbital of S and the 2p orbital of O shapes overlap significantly around -5 eV. The orbital hybridization occurs when the O atom interacts with the S atom, indicating that the interaction between SnS₂ and CuO atom mainly comes from the S atom and the O atom.

3.2. NH_3 , Cl_2 , and C_2H_2 Adsorption on TMO-SnS₂ Surfaces. To study the adsorption characteristics of NH_3 , Cl_2 , and C_2H_2 on TMO-SnS₂, the gas molecules were adsorbed on the TMO-SnS₂ surface from different directions and angles. The most stable gas adsorption structures on Ag₂O and CuO–



Figure 2. Most stable structure of the (a) Ag₂O-SnS₂ surface and (b) CuO-SnS₂ surface. The distance is in Å.



Figure 3. TDOS and PDOS of before and after gas molecule adsorption on (a) Ag₂O-SnS₂ and (b) CuO-SnS₂.

 SnS_2 surfaces are shown in Figures 3 and 5, respectively. The density of states, band structure, and molecular orbital of the adsorption process were analyzed by taking the most stable adsorption structure that has the largest adsorption energy.

3.2.1. Gas Adsorption on the Ag_2O-SnS_2 Surface. The adsorption distances of NH₃, Cl₂, and C₂H₂ on Ag₂O-SnS₂ are 1.754, 1.724, and 1.905 Å, respectively. The structures of NH_3 and C_2H_2 gas molecules stay intact in the adsorption process, but the Cl–Cl bond breaks in the adsorption process of Cl₂. It can be seen that the adsorption distance of NH_{3} , Cl_{2} , and $C_{2}H_{2}$ by $Ag-SnS_2$ is relatively moderate, which is conducive to the subsequent desorption, making the recycling of sensing material and improving the sensitivity of the gas sensor. In the adsorption process of NH₃ gas, the H atom is absorbed on the O atom; it can be speculated that there is a chemical bond between the H atom and the O atom because when N atoms and H atoms combine to form NH₃, N atoms have a larger radius and are less likely to lose electrons and gain electrons, while H atoms have a smaller radius and possess more ability to lose electrons. As can be seen from the previous paper, in the doping process of Ag_2O on SnS_2 , the O atom gains electrons, thus making the O atom

show more electrons to bond with the H atom that lost electrons. This is the mechanism in which the H atom approaches Ag_2O-SnS_2 , while the N atom is far away from the Ag_2O-SnS_2 . It can be seen that the adsorption of NH_3 , Cl_2 , and C_2H_2 by Ag_2O-SnS_2 belongs to chemical adsorption. In addition, when Ag_2O-SnS_2 adsorbed Cl_2 gas, the chemical bond between Cl-Cl was broken due to excessive adsorption energy and charge transfer, so the adsorption was not reversible. After adsorption, the modified SnS_2 substrate was in a state that could not be reused. The adsorption of the other two gases can be desorbed for recycling applications.

Figure 5 shows the TDOS and PDOS before and after adsorption of NH₃, Cl₂, and C₂H₂ by Ag₂O–SnS₂, where dotted lines represent the Fermi levels. It can be seen in Figure 5a1–c1 that the peak value of the TDOS shifts significantly to the left after adsorption, making it continuous at the Fermi level. In Figure 5a1,b1, it can be seen that Ag_2O –SnS₂ generates a new peak value at –5.0 to –7.5 eV due to the hybridization of Ag 4d, N 2p, O 2p, and H 1s in the adsorption process of NH₃. In Figure 4a2,b2, it can be seen that during the adsorption of Ag 4d, O



Figure 4. Most stable structures of gas molecules on Ag_2O-SnS_2 : (a) Ag_2O-SnS_2/NH_3 , (b) Ag_2O-SnS_2/Cl_2 , and (c) Ag_2O-SnS_2/C_2H_2 . The distance is in Å.

2p, and Cl 3p at -0 to -5.0 eV. In Figure 5a3–b3, Ag₂O–SnS₂ generates a new peak due to the hybridization of Ag 4d, C 2p, O 2p, and H 1s at -5.0 to -10.0 eV during the adsorption of C₂H₂. The generation of the new peak value makes the chemisorption more stable, and the larger the overlapping peak value, the stronger the chemical interaction. In Figure 5b1, it can be seen that the peak value of the overlap is very large when Ag₂O–SnS₂ adsorbs Cl₂, which also confirms that the adsorption chemistry of Cl₂ is very strong, leading to the rupture of the Cl–Cl chemical bond. However, Ag₂O–SnS₂ has no new peak value for C₂H₂, which also confirms that the chemical adsorption of C₂H₂ is too weak, making C₂H₂ desorb easily.

The adsorption parameters of Ag_2O-SnS_2 for the three gases are shown in Table 1, including the adsorption distance, adsorption energy, and charge transfer. The adsorption energies of the NH₃, Cl₂, and C₂H₂ adsorption structures are -0.463, -0.742, and -0.354 eV, in which the negative adsorption energy means that the reaction can be spontaneous. Therefore, Ag_2O- SnS₂ has moderate adsorption energy for NH₃, Cl₂, and C₂H₂, which will not be too large for hard desorption nor too small to detect these three gases due to low adsorption energy. The charge transfer of the three adsorption structures during the adsorption process is 0.138 e, -0.176 e, and 0.013 e, in which the negative charge transfer represents the transfer of electrons from gas to Ag_2O-SnS_2 , while the positive charge transfer represents the transfer of electrons from Ag_2O-SnS_2 to gas molecules.

3.2.2. Gas Adsorption on the CuO-SnS₂ Surface. As the adsorption structures shown in Figure 6, the distances of NH₃, Cl₂, and C₂H₂ on the CuO-SnS₂ substrate are 2.266, 2.168, and 2.277 Å, respectively. It can be seen that the structures of the three gas molecules and CuO-SnS₂ are kept intact when gas molecules are adsorbed on the surface of CuO-SnS₂. The adsorption distance, adsorption energy, and charge transfer of the three gas adsorption structures are listed in Table 2. In the adsorption process of CuO-SnS₂ toward NH₃ gas, H atoms are close to the substrate, while N atoms stay far away. The large adsorption distance of CuO-SnS₂ to NH₃ can be inferred as physical adsorption. In the adsorption process of Cl₂ gas, the Cl atom closes to the Cu atom because of the abundant

electronegativity of the Cl atom and the abundant positive charge of the Cu atom. In the adsorption process of C_2H_2 gas, the H atom is absorbed on the O atom of CuO. This is because when C and H combine to form C_2H_2 , C has a larger radius and is less likely to lose electrons and gain electrons, while H has a smaller radius and is more likely to lose electrons. The adsorption energies of NH₃, Cl₂, and C₂H₂ gases are -0.327, -0.925, and -0.299 eV, respectively. Charge transfer is 0.046 e, -0.115 e, and -0.072 e, respectively.

Figure 7 shows the TDOS and PDOS before and after CuO– SnS₂ adsorbs NH₃, Cl₂, and C₂H₂, where dotted lines represent Fermi energy levels. It can be seen in Figure 7a1–c1 that the peak value of the total density of states shifts significantly to the left after adsorption, making it continuous at the Fermi level. As can be seen from Figure 7a1,b1, CuO–SnS₂ generated a new peak value at -5.0 to -7.5 eV due to the hybridization of Cu 4s, N 2p, O 2p, and H 1s in the adsorption process of NH₃. In Figure 7a2,b2, it can be seen that CuO–SnS₂ generates a new peak value due to the hybridization of Cu 4s, O 2p, and Cl 3p at -2.5to -5.0 eV during the adsorption of Cl₂. In Figure 7a3–b3, it can be seen that CuO–SnS₂ generates a new peak due to the hybridization of Cu 4s, C 2p, O 2p, and H 1s at -7.5 to -10.0 eV during C₂H₂ adsorption.

The adsorption parameters of CuO–SnS₂ for the three gases are shown in Table 1, including adsorption distance, adsorption energy, and charge transfer. The adsorption energies of the three adsorption structures are -0.327, -0.925, and -0.299 eV in order, in which the negative adsorption energy means that the reaction can be spontaneous. Therefore, it can be seen that CuO–SnS₂ has moderate adsorption energy for NH₃, Cl₂, and C₂H₂ and does not generate large adsorption energy so that NH₃, Cl₂, and C₂H₂ gases cannot be desorbed nor can it detect these three gases due to low adsorption energy. The charge transfer of the three adsorption structures is 0.046 e, -0.115 e, and 0.072 e respectively.

3.3. Molecular Orbital Theory Analysis of Gas Adsorption on Ag₂O-SnS₂ and CuO-SnS₂. The behavior of system electrons in the adsorption process was analyzed by frontier molecular orbital theory, and HOMO and LUMO after



Figure 5. TDOS and PDOS of before and after gas molecule adsorption on Ag₂O-SnS₂.

 Table 1. Adsorption Parameters of Gas Molecules on Ag₂O-SnS₂

configuration	structure	d (Å)	$E_{\rm ads}~({\rm eV})$	$Q_{\mathrm{T}}\left(\mathbf{e}\right)$
Ag_2O-SnS_2/NH_3	Figure 4a	1.754	-0.463	0.138
Ag_2O-SnS_2/Cl_2	Figure 4b	1.724	-0.742	-0.176
Ag_2O-SnS_2/C_2H_2	Figure 4c	1.905	-0.354	-0.013

adsorption of NH₃, Cl₂, and C₂H₂ gases were obtained, as shown in Figures 8 and 9. Since the HOMO is denser, the system is more likely to give away electrons, whereas since LUMO is less dense, the electron affinity is stronger, and the size of the energy gap can be an indicator of a system's conductivity. The increase in metal oxide doping can reduce E_g and thus increase the conductivity.

Before Ag_2O-SnS_2 adsorbs gas, HOMO is mainly distributed on Ag, indicating that the Ag atom provides electrons as electron donors and is also the active site that can provide adsorption sites for NH₃, Cl₂, and C₂H₂ gases. After adsorption of NH₃, Cl₂, and C₂H₂ gases, HOMO becomes more concentrated on Ag, while LUMO becomes more uniform. The band gaps of Ag₂O– SnS₂ adsorbed by the three gases are 0.016, 0.025, and 0.019 eV, as shown in Table 3, respectively. The HOMO and LUMO distribution on the Ag atom after Ag_2O-SnS_2 is adsorbed by NH_3 is very small, indicating that the electron distribution of the system is more uniform. The moderate band gap also indicates that Ag_2O-SnS_2 is more suitable for the gas sensor of NH_3 .

HOMO is mainly distributed on Cu before CuO-SnS₂ adsorbs gas, indicating that the Cu atom provides electrons as electron donors and is also the active site to provide adsorption sites for NH₃, Cl₂, and C₂H₂ gases. After adsorption of NH₃, Cl₂, and C₂H₂ gases, HOMO changes become more concentrated on Cu, while LUMO becomes more uniform. Moreover, the change is most obvious after the adsorption of Cl₂ gas. It can be seen from the above that this is due to the strong interaction of molecular orbitals after CuO-SnS₂ adsorption on Cl₂, which makes HOMO and LUMO more homogeneous. In addition, there is almost no LUMO on CuO, which is also due to the strong chemical interaction between CuO and Cl₂ gas, making CuO relatively stable. However, when CuO-SnS₂ adsorbs C₂H₂, LUMO still exists in large quantities on CuO, which is caused by the weak interaction between C₂H₂ and CuO. As shown in Table 4, the band gaps of $CuO-SnS_2$ adsorbed by the



Figure 6. Most stable structures of gas molecules on $CuO-SnS_2$. (a) $CuO-SnS_2/NH_{3'}$ (b) $CuO-SnS_2/Cl_{2'}$ (c) $CuO-SnS_2/C_2H_2$. The distance is in Å.



Figure 7. TDOS and PDOS of before and after gas molecule adsorption on CuO-SnS₂.

Table 2. Adsorption Parameters of Gas Molecules on CuO– ${\rm SnS}_2$

configuration	structure	d (Å)	$E_{\rm ads}~({\rm eV})$	$Q_{\mathrm{T}}\left(\mathbf{e}\right)$
CuO-SnS ₂ /NH ₃	Figure 6a	2.266	-0.327	0.046
$CuO-SnS_2/Cl_2$	Figure 6b	2.168	-0.925	-0.115
$\rm CuO-SnS_2/C_2H_2$	Figure 6c	2.277	-0.299	0.072



Figure 8. HOMO and LUMO of Ag₂O-SnS₂ and adsorption systems.



Table 3. Energy of HOMO, LUMO, and the Energy Gap of Ag₂O-SnS₂ and Adsorption Systems

structure	$E_{\rm HOMO}~({\rm eV})$	$E_{\rm LUMO}~({\rm eV})$	$E_{\rm g}~({\rm eV})$
Figure 8a	-0.212	-0.196	0.016
Figure 8b	-0.226	-0.201	0.025
Figure 8c	-0.220	-0.201	0.019
	structure Figure 8a Figure 8b Figure 8c	structure E _{HOMO} (eV) Figure 8a -0.212 Figure 8b -0.226 Figure 8c -0.220	structure E_{HOMO} (eV) E_{LUMO} (eV) Figure 8a -0.212 -0.196 Figure 8b -0.226 -0.201 Figure 8c -0.220 -0.201

Table 4. Energy of HOMO, LUMO, and the Energy Gap of CuO–SnS₂ and Adsorption Systems

configuration	structure	$E_{\rm HOMO}~({\rm eV})$	$E_{\rm LUMO}~({\rm eV})$	$E_{\rm g}~({\rm eV})$
$CuO-SnS_2/NH_3$	Figure 9a	-0.196	-0.191	0.005
$CuO-SnS_2/Cl_2$	Figure 9b	-0.206	-0.199	0.007
$CuO{-}SnS_2/C_2H_2$	Figure 9c	-0.189	-0.182	0.007

three gases are 0.005, 0.007, and 0.007 eV, respectively. The HOMO and LUMO distribution on Cu atoms after $CuO-SnS_2$ is adsorbed by C_2H_2 is very small, indicating that the electron distribution of the system is more uniform. The moderate band

gap also indicates that $\rm CuO-SnS_2$ is more suitable for the $\rm C_2H_2$ gas sensor.

4. CONCLUSIONS

In this paper, the adsorption properties of Ag₂O-SnS₂ and CuO-SnS₂ for NH₃, Cl₂, and C₂H₂ gases were calculated based on first principles. First, the most stable structures of the Ag₂O and CuO modification on SnS2 were analyzed with various doping sites. The introduction of Ag₂O and CuO metal oxide doping increases the conductivity of SnS₂-based materials. Then, the interaction between Ag₂O and CuO-modified SnS₂ and gas molecules was comprehensively understood by the adsorption structure, the density of states, and frontier molecular orbital theory. Ag₂O-SnS₂ and CuO-SnS₂ structures are chemisorbed for NH₃, Cl₂ and C₂H₂ gases. From a moderate adsorption distance, large adsorption energy, charge transfer, and frontier molecular orbital theory analysis, different gas molecules' adsorption will induce changes in conductivity to different degrees. As a result, Ag₂O-SnS₂ is suitable for the NH₃ gas sensor, while $CuO-SnS_2$ is suitable for the C_2H_2 gas sensor. Under the doping of Ag₂O and CuO, the adsorption process mechanism and adsorption capacity are slightly different, but the adsorption of NH₃, Cl₂, and C₂H₂ is consistent. Ag₂O and CuOmodified SnS_2 is a suitable gas sensor and has a promising application in greenhouse cultivation.

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Notes

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